

# MSIM<sup>®</sup>

*High Accuracy Spice Simulator*

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*Technology Leader in IP Characterization and IC/PCB Simulation*

**Legend**  
Design Technology

# Legend's Products

## ◆ IP Library Characterization Products

- Charflo-Cell!<sup>TM</sup>: *Automatic Cell/IO Library Characterization*
- Charflo-Memory!<sup>TM</sup>: *Automatic Memory Characterization*

## ◆ IP Library Model Qualify Assurance Products

- Model Diagnoser<sup>TM</sup>  
*Cell/IO Library Quality Assurance and Defect Repair*

## ◆ Circuit Simulation Products

- MSIM<sup>®</sup>: *Accurate-Spice Simulator*
- Turbo-MSIM<sup>TM</sup>: *Fast-Spice Simulator*



# MSIM<sup>®</sup>

## High Accuracy Spice Simulator

- ◆ Extreme accuracy and excellent convergence
- ◆ High speed and large capacity
- ◆ Extensive model support
- ◆ Multi-threaded applications on multi-core computer
- ◆ Automatic matrix solver selector for throughputs
- ◆ Built-in AWE RC Reduction
- ◆ Best price-performance

# MSIM<sup>®</sup> Certifications

- ◆ MSIM certified by TSMC's Spice Tool Qualification Program

*<http://www.legenddesign.com/BW/021009.shtml>*

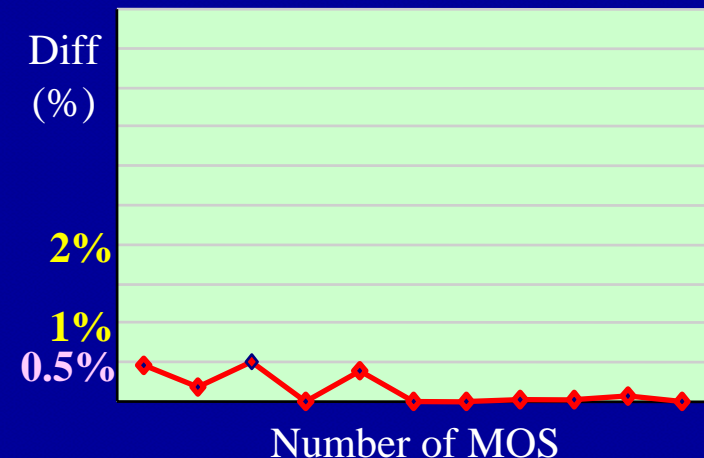
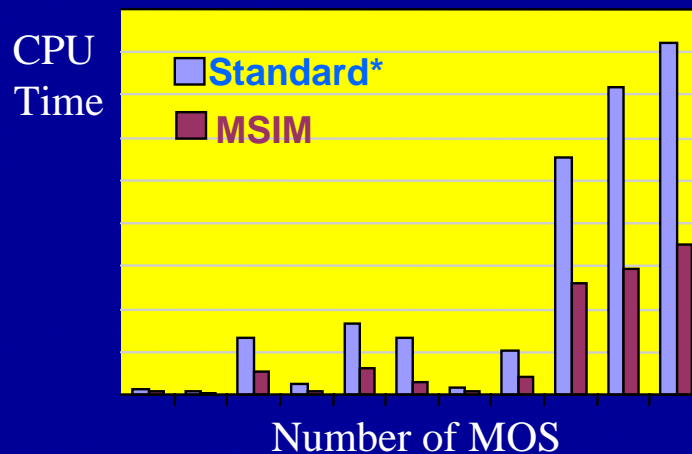
- ◆ MSIM certified by TSMC's TMI (TSMC Model Interface) Qualification Program



# MSIM<sup>®</sup> Advantages

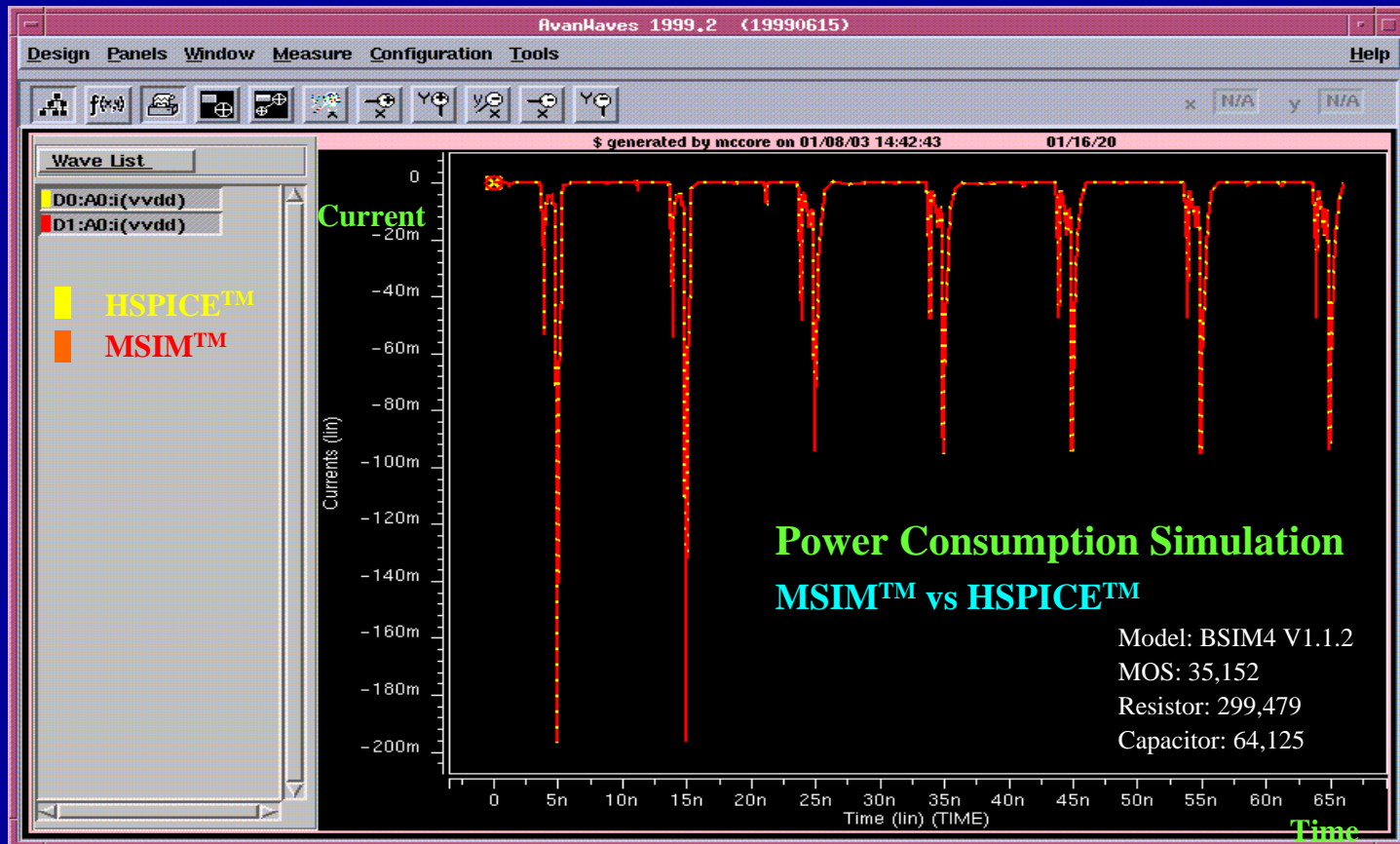
## High Accuracy and Fast Speed

- More than twice the speed of the Standard\*
- Same accuracy (less than 1%) as the Standard\*



\* Standard means the most popular Spice simulator

# MSIM<sup>®</sup> Accuracy Benchmark on BSIM4 Model



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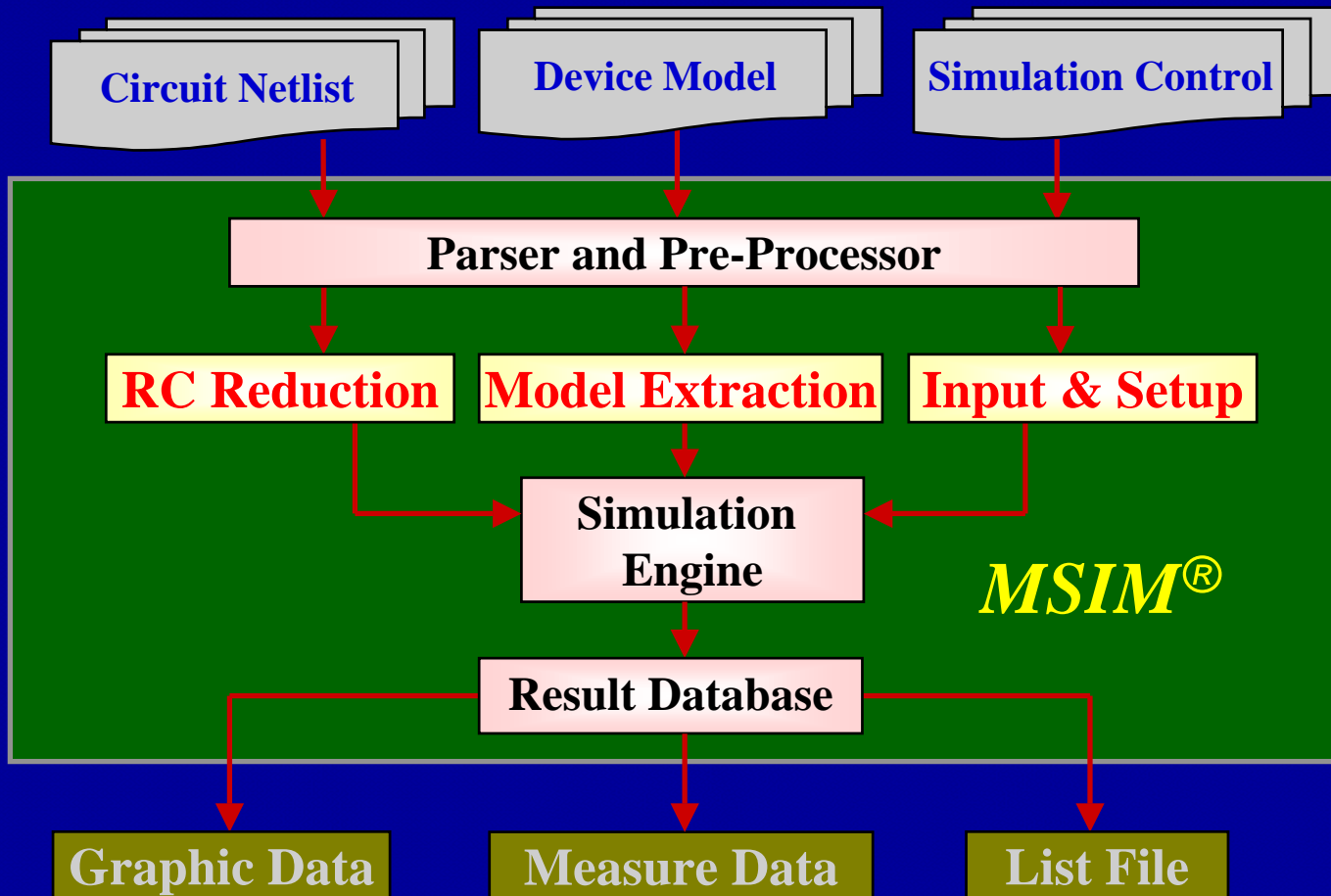


# MSIM<sup>®</sup> Model Support

## Extensive Modeling Support

- ◆ MSIM delivers silicon-accurate models with proven implementations of
  - \* BSIM3
  - \* BSIM4
  - \* BSIM4 SOI
  - \* HiSIM1 and HiSIM2
  - \* Philips MM9 & MM11
  - \* RPI TFT
- ◆ Direct access of updated SPICE models from
  - \* TSMC
  - \* UMC
  - \* IBM
  - \* Chartered
  - \* SMIC
  - \* Tower

# MSIM<sup>®</sup> Simulation Flow





# MSIM<sup>®</sup> Multi-Thread

## Multi-Core and Parallelism Support

- ◆ Enable multi-threaded application on a multi-core configuration
- ◆ Utilize the multi-thread functions for decomposing and solving matrices, and calculating device model
- ◆ Prove its outstanding efficiency on the circuits with a large number of extracted post-layout parasitics

# MSIM<sup>®</sup> Multi-Thread Benchmark Data

- ◆ Benchmark on 2 Quad-Core CPU system

Threads	Run Time	Speed-up
1	319 seconds	1.00 X
2	171 seconds	1.87 X
3	121 seconds	2.64 X
4	97 seconds	3.29 X
5	80 seconds	3.99 X
6	68 seconds	4.69 X
7	64 seconds	4.98 X
8	57 seconds	5.60 X



# MSIM<sup>®</sup> Maxtrix Solving

## Automatic Matrix Solver Selector

- ◆ Conventionally, sparse matrix solving technique is used to take advantage of the sparse in circuit matrix for the efficiency
- ◆ For nanometer technology, sparse matrix solving technique could be not efficient for the layout extracted circuits with large RC networks
- ◆ A Matrix Solver Selector has been developed and implemented in MSIM, for simulation throughputs.

# MSIM<sup>®</sup> Maxtrix Solving

## Benchmark Data

- ◆ Benchmark circuit data  
MOSFET: 6,926   Resistor: 65,662   Capacitor: 11,178
- ◆ Simulation statistics using Sparse Matrix  
Max allocated memory = 251 mb  
Total CPU time = 36,092.59 seconds
- ◆ Simulation Data using Matrix Solver Selector  
Max allocated memory = 97 mb  
Total CPU time = 2,589,.69 seconds
- ◆ **14X** Speed up, and **2.6X** less usage of memory



# MSIM<sup>®</sup> RC Reduction

## Layout-Extracted Circuit Simulation

- ◆ Benchmark on D-Type Flip Flop circuit

MOSFET: 18                      Resistor & Capacitor:                      1,000+

	Standard*	MSIM <sup>™</sup>	Comparison
CPU Time	300 sec	<b>10 sec</b>	<b>30 X</b>

**The inaccuracy is less than 1%.**

- ◆ Benchmark on SRAM 'RR256x16'

MOSFET: 39,464      Resistor : 200,526      Capacitor: 316,934

	Standard*	MSIM <sup>™</sup>	Comparison
Accuracy	3.41 ns	<b>3.39 ns</b>	<b>0.59 %</b>
CPU Time	3,867 sec	<b>317 sec</b>	<b>12.2 X</b>

\* Standard means the most popular Spice simulator

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# Subcircuit Spice Model

## Memory Usage/CPU Time Benchmark

- ◆ Subcircuit Spice models are popular in 65nm and below due to its flexibility. Each MOSFET has its own model.
- ◆ Subcircuit Spice models cause huge memory usage and degrade the performance.

Circuit Type	MOSFET Count	MSIM		Other Popular Spice	
		CPU Time	Memory Usage	CPU Time	Memory Usage
Data_in.sp	~10K	551 sec	293 MB	2,294 sec	6.7 GB
Access.sp	~40K	3,007 sec	1.4 GB	Can not run	Can not run



# MSIM®

## Applications in IC and IP

- ◆ Analog circuit design verification
  - Frequency response and transient analysis for verifying analog circuits like PLL, A/D and D/A converters, amplifiers and IO devices etc.
- ◆ Mixed-signal circuit design verification
  - Support Verilog-A behavioral modeling, vector input stimulus and vector output verification
- ◆ RF design analysis
- ◆ Cell library and memory characterization

# MSIM<sup>®</sup>

## Ring Oscillator Benchmark

101 Stage NAND2 Ring Oscillator Simulation Results / Comparison

Measurement	Standard* Accurate Mode*	MSIM Accurate Mode	
	Time	Time	Difference
Time_rr	4.2711e-09	4.2527e-09	0.43%
Time_ff	4.2711e-09	4.2520e-09	0.45%
Average Current	-1.4119e-04	-1.4096e-04	0.16%
Power Parameter	-7.2364e-13	-7.1936e-13	0.59%
Time_rf	2.1422e-09	2.1325e-09	0.45%
Duty Parameter	5.0156e+01	5.0144e+01	0.02%

MSIM (Accurate Mode)

98.23 sec

Standard\* (Accurate Mode)

328.68 sec

**MSIM Speed-Up**

**3.35 X**

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## Memory Benchmark

Full-Circuit 'Access Time' Simulation Results / Comparison

*This SRAM circuit has 21,087 MOS, 73,374 Rs and 44,639 Cs*

Access Time	Standard* Accurate Mode	MSIM Accurate Mode		HSPICE Default Mode		MSIM Default Mode	
	Time	Time	Difference	Time	Difference	Time	Difference
O[0] rise	<b>1.4776ns</b>	1.4769ns	<b>-0.0474%</b>	1.4541ns	<b>-1.5904%</b>	1.4849ns	<b>0.4940%</b>
O[24] rise	<b>1.4832ns</b>	1.4823ns	<b>-0.0607%</b>	1.4560ns	<b>-1.8339%</b>	1.4880ns	<b>0.3236%</b>
O[0] fall	<b>1.5448ns</b>	1.5441ns	<b>-0.0453%</b>	1.5219ns	<b>-1.4824%</b>	1.5552ns	<b>0.6732%</b>
O[24] fall	<b>1.5446ns</b>	1.5445ns	<b>-0.0065%</b>	1.5221ns	<b>-1.4567%</b>	1.5633ns	<b>1.2107%</b>

Standard\* Accurate Mode is taken as 'GOLD' for comparison

*\* Standard means the most popular Spice simulator*

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## Phase Locked Loop Benchmark

### 250MHz PLL Circuit Simulation Results /Comparison

Measurement	Standard* Accurate Mode	MSIM Accurate Mode	
	Time	Time	Difference
Lock Time	<b>2.0040e-06</b>	2.0038e-06	<b>0.01%</b>
Last Single Clock Cycle Time	<b>3.9999E-09</b>	3.9971e-09	<b>0.07%</b>
Average Clock Cycle Time	<b>4.0000E-09</b>	3.9998e-09	<b>0.00%</b>
Power	<b>3.2518e-04</b>	3.2295e-04	<b>0.69%</b>

MSIM (Accurate Mode)

2794 seconds

Standard\* (Accurate Mode)

6096 seconds

**MSIM Speed-Up**

**2.16 X**

*\* Standard means the most popular Spice simulator*

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## Complex IO Circuit Benchmark

### Complex IO Circuit Simulation Results / Comparison

Measurement	Standard* Accurate Mode	MSIM Accurate Mode	
	Time	Time	Difference
Rise delay	1.095e-09	1.095e-09	0.00%
Fall delay	1.007E-09	1.0071e-09	0.01%
Rise slew	2.489E-09	2.496e-09	0.26%
Fall slew	2.493e-09	2.498e-04	0.22%

MSIM (default Mode)

**33.94 seconds**

Standard\* (default Mode)

**1,550.14 seconds**

**MSIM Speed-Up**

**45.5 X**

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# Special Model Interface

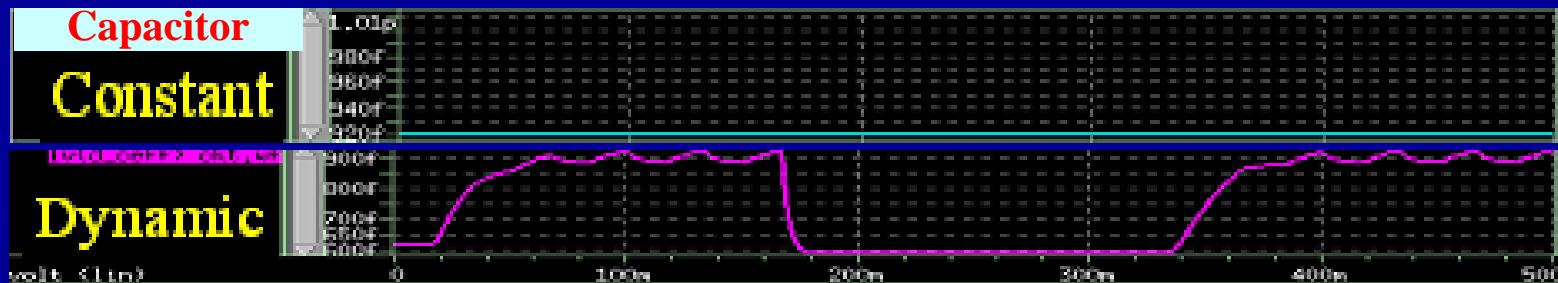
- ◆ Verilog-A model
- ◆ CMI (Common Model Interface) model
- ◆ TMI (TSMC Model Interface) model
- ◆ LCD Panel model
- ◆ S-Parameter model



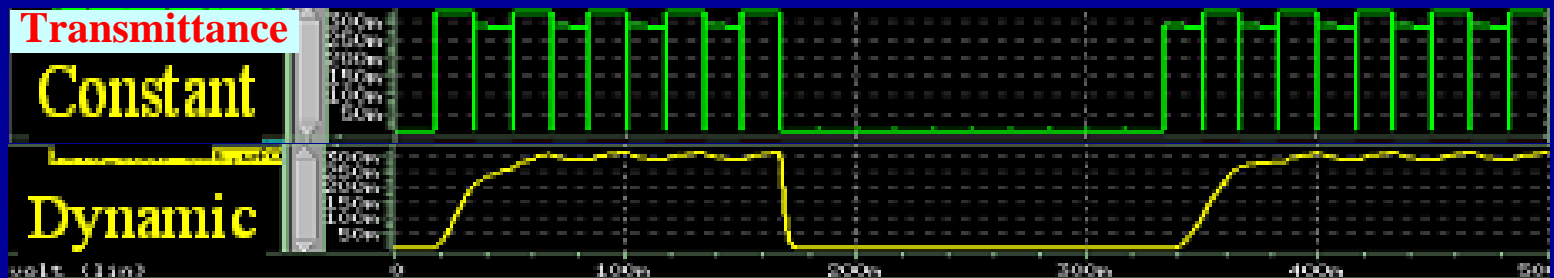
# LCD Panel Circuit Simulation

## Dynamic $C_{LC}$ and Advanced TFT Model

- ◆ Dynamic effect of Effective Capacitor can be simulated by MSIM

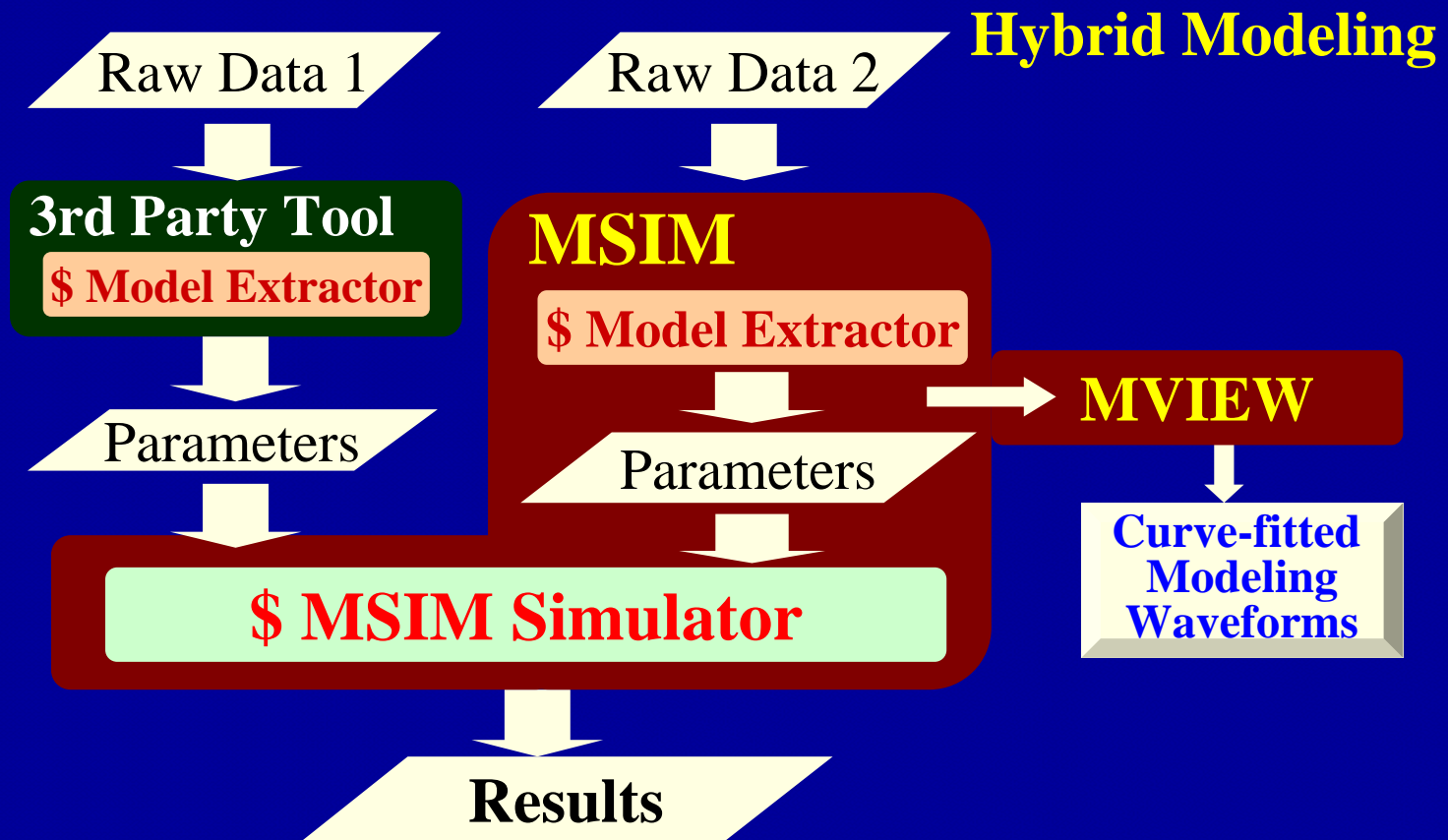


- ◆ Dynamic effect of Transmittance can be simulated by MSIM



# Hybrid Modeling Flow

A Complete Device Modeling Solution

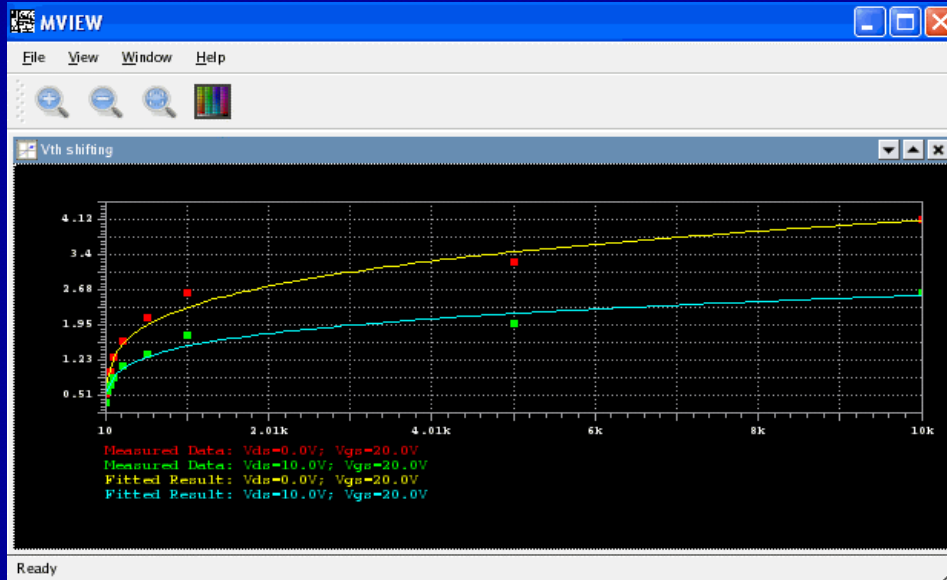




# Hybrid Modeling Example

## Model Parameters by Curve Fitting

Advanced Threshold Voltage Shift Model

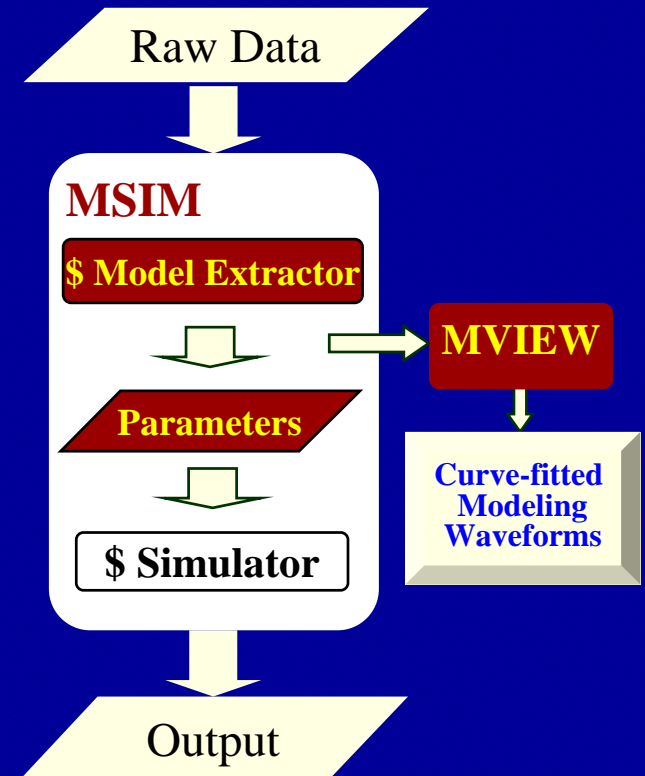


Parameters extracted from MSIM built-in Model Extractor by curve-fitting

$$A = 0.0280863$$

$$\beta = 0.247142$$

MSIM Hybrid Flow



# MSIM<sup>®</sup> for Optimization

- ◆ A procedure for automatic searching instance or model parameters to meet design goal
- ◆ Optimization function can be applied for .DC, .AC and .TRAN analysis
- ◆ Optimization method can be native, bi-section or pass-fail
- ◆ Flexible measurements in optimization process
- ◆ HSPICE-compatible format



# MSIM<sup>®</sup> Portability

## ◆ Platforms

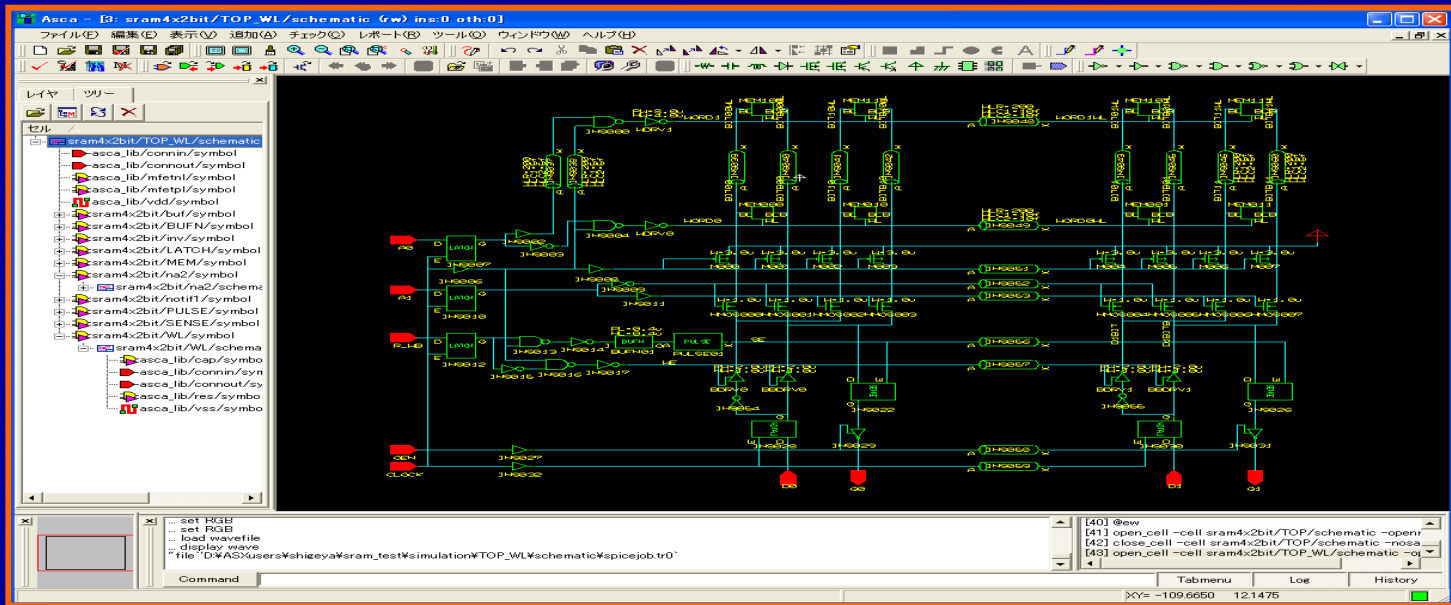
- Redhat Enterprise Linux
- Windows XP
- Solaris on X86

## ◆ Environments

- JEDAT - ASCA
- SpringSoft – Laker-ADP
- Cadence - ADE
- Mentor – DAIC

# MSIM<sup>®</sup> with ASCA

## Jedat's AnalogCreator Platform



MSIM seamlessly integrated into Jedat's ASCA with

- High throughputs
- Optimized simulation and debugging setup

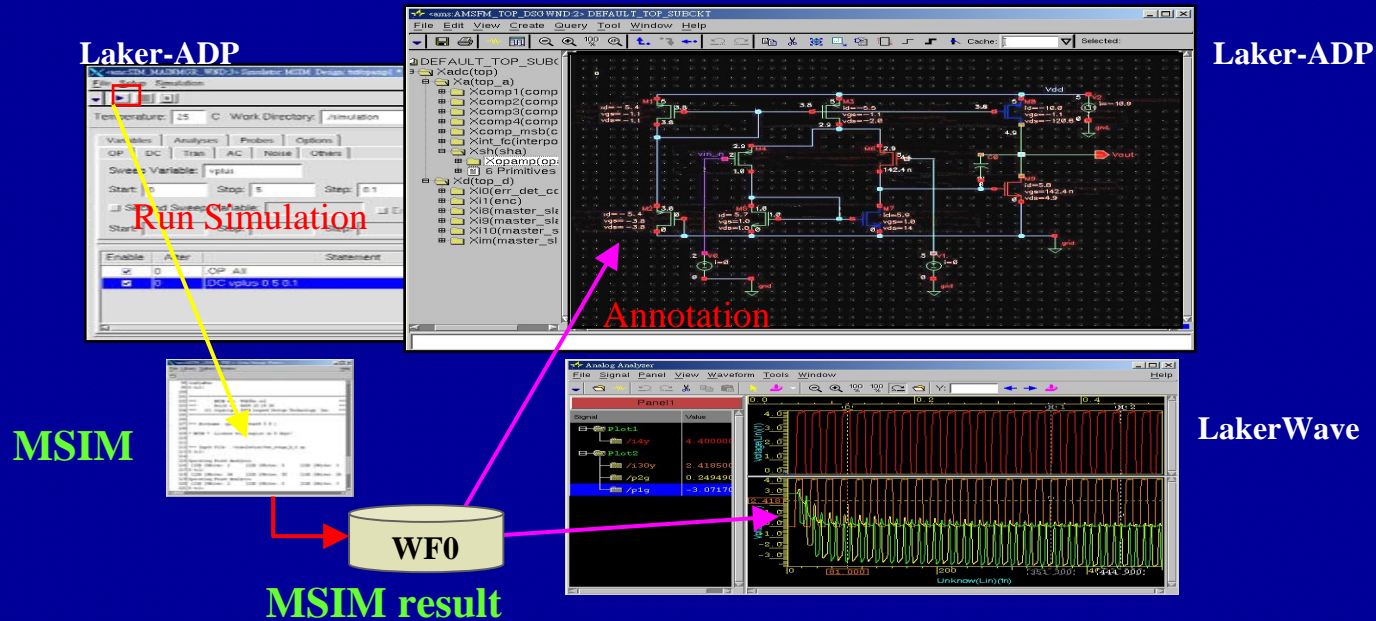
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# MSIM<sup>®</sup> with Laker-ADP

## Silicon Canvas' Analog Design Platform



MSIM seamlessly integrated into Laker-ADP with

- Enhanced productivity
- Speedup of simulation and debugging process

# MSIM<sup>®</sup> with Virtuoso

## ◆ MSIM-Virtuoso Ocean Interface

- The input to MSIM is the circuit netlist from Virtuoso database, and simulation controls from users
- The output from MSIM is the measurement, the list and waveform files including PSF format

## ◆ MSIM-Virtuoso ADE Interface

- MSIM is fully compatible with HSPICE options including option ARTIST and PSF.
- MSIM can be invoked in the same way as HSPICE does from ADE, after some simple environment setup.



# MSIM<sup>®</sup> for Characterization

## Cell / IO / Memory Characterization

- ◆ Standard / IO Cell Library Characterization
  - Legend Design Technology's CharFlo-Cell!
  - Magma's SiliconSmart
  - Cadence' SignalStorm
  - Library Technology's LibChar
  - In-house characterization tools
- ◆ Memory Compiler Characterization
  - Legend Design Technology's CharFlo-Memory!
  - In-house characterization tools

# MSIM<sup>®</sup> with CharFlo-Cell!

## Cell/ IO Library Characterization

- ◆ The integration of CharFlo-Cell! products and MSIM has been successfully completed
- ◆ MSIM has been the primary circuit simulator used in QA flow of CharFlo-Cell! products
- ◆ The speed and accuracy of MSIM complements the strengths of the CharFlo-Cell! technology
- ◆ MSIM circuit simulator runs multiple times faster than traditional SPICE simulators without loss of accuracy



# MSIM<sup>®</sup> with Charflo-Memory!

## Memory IP Characterization

### ◆ Register File 'RF2R1W16X128S'

**Access Time (5 input slopes and 5 output loadings)**

**25 Simulation Jobs**

	<b>CPU Time</b>	<b>Gains</b>
<b>1 MSIM<sup>®</sup></b>	7 Hours 17 Minutes	<b>1.0 X</b>
<b>4 MSIM<sup>®</sup></b>	2 Hours 8 Minutes	<b>3.4 X</b>
<b>8 MSIM<sup>®</sup></b>	1 Hour 13 Minutes	<b>6.0 X</b>
<b>25 MSIM<sup>®</sup></b>	18 Minutes	<b>23.9X</b>

# MSIM<sup>®</sup> Compatibility

- ◆ HSPICE format

*Command*

```
% msim -i ckt.sp -o ckt.lis -hsp
```

The flag *-hsp* turns on HSPICE format and output naming convention

- ◆ Spectre Format

*Command*

```
% msim -i ckt.sp -o ckt.lis -spectre
```

The flag *-spectre* turns on Spectre format.

- ◆ Eldo Format

*Command*

```
% msim -i ckt.sp -o ckt.lis -eld
```

The flag *-eld* turns on Eldo format and output naming convention



# Conclusion

- ◆ MSIM is an excellent circuit simulator by
  - Innovative algorithms and schemes
  - Optimized codes and structures
  - Silicon-accurate BSIM3 and BSIM4 modeling
- ◆ MSIM certified by TSMC Spice Tool Qualification
- ◆ MSIM supports multi-threaded applications on a multi-core computer, with flexible licensing
- ◆ MSIM automates the selecting matrix solver for layout-extracted circuits, with much higher speed-up
- ◆ MSIM provides best price-performance